UNISONIC TECHNOLOGIES CO., LTD

MMBTA55

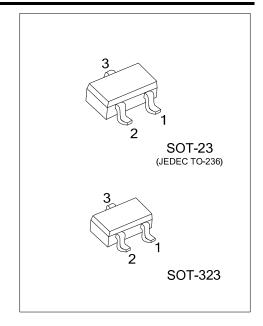
Preliminary

AMPLIFIER TRANSISTOR

PNP MMBTA55

FEATURES

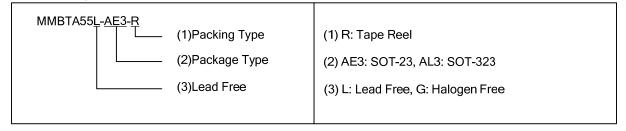
* Collector-Emitter Voltage: V_{CEO}=60V



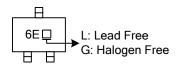
ORDERING INFORMATION

Ordering Number		Dooksons	Pin Assignment			Dacking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MMBTA55L-AE3-R	MMBTA55G-AE3-R	SOT-23	Е	В	С	Tape Reel	
MMBTA55L-AL3-R	MMBTA55G-AL3-R	SOT-323	E	В	С	Tape Reel	

Note: Pin assignment: E: EMITTER, C: COLLECTOR, B: BASE



MARKING



www.unisonic.com.tw 1 of 3

■ **ABSOLUTE MAXIMUM RATING** (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-base voltage		V_{CBO}	60	V	
Collector-emitter voltage		V_{CEO}	60	V	
Emitter-base voltage		V_{EBO}	4	V	
Collector current - Continuous		I _C	500	mA	
Total device dissipation	T _A =25°C	P _D	350	mW	
	Derate above 25°C		2.8	mW/°C	
Junction Temperature		TJ	125	°C	
Storage Temperature		T _{STG}	-40 ~ +150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ_{JA}	357	°C/W	

Note: $R_{\theta JA}$ is measured with the device soldered into a typical printed circuit board.

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNI T		
OFF CHARACTERISTICS								
Collector-emitter breakdown voltage (note 1)	$V_{(BR)CEO}$	I _C =1.0mA, I _B =0	60			V		
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I _E =100μA, Ic=0	4			V		
Collector cutoff current	I _{CES}	V _{CE} =60V, I _B =0			0.1	μΑ		
Collector cutoff current	I _{CBO}	V _{CB} =60V, I _E =0			0.1	μΑ		
ON CHARACTERISTICS								
DC gurrant gain	h	I _C =10mA, V _{CE} =1V	100					
DC current gain	h _{FE}	I _C =100mA, V _{CE} =1V	100					
Collector-emitter saturation voltage	$V_{CE(SAT)}$	I _C =100mA, I _B =10mA			0.25	V		
Base-emitter on voltage	$V_{BE(ON)}$	I _C =100mA, V _{CE} =1V			1.2	V		
SMALL-SIGNAL CHARACTERISTICS								
Current gain bandwidth product (note 2)	f⊤	I _C =100mA, V _{CE} =1V, f=100MHz	50			MHz		

Note 1. Pulse test: PW<=300μs, Duty Cycle<=2%

^{2.} f_T is defined as the frequency at which Ihfel extrapolates to unity.

■ SWITCHING TIME TEST CIRCUIT

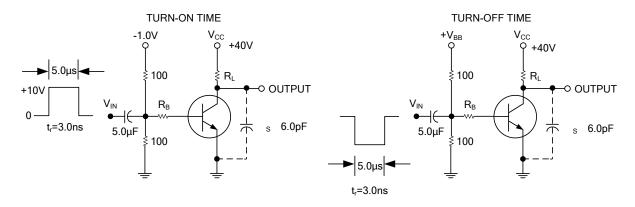


Figure 1. (Note: Total shunt capacitance of test jig and connectors for PNP test circuits, reverse all voltage polarities.)

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.